MAX77801

High-Efficiency Buck-Boost Regulator

General Description

The MAX77801 is a high-current, high-efficiency buck-boost targeted to mobile applications that use a Li-ion battery or similar chemistries. The MAX77801 utilizes a four-switch H-bridge configuration to support buck and boost operating modes. Buck-boost provides 2.60V to 4.1875V of output voltage range and up to 2A output current.

A unique control algorithm allows high efficiency, outstanding performances in line/load transient response, and seamless transition between buck and boost modes.

DVS (dynamic voltage scaling) input allows the host processor to switch between two preprogrammed output voltages. This feature minimizes power loss for given load conditions. The ramp-up and ramp-down slew rates are programmable through I²C.

The MAX77801 features I²C-compatible, 2-wire serial interface consisting of a bidirectional serial-data line (SDA) and a serial-clock line (SCL). It supports SCL clock rates up to 3.4MHz.

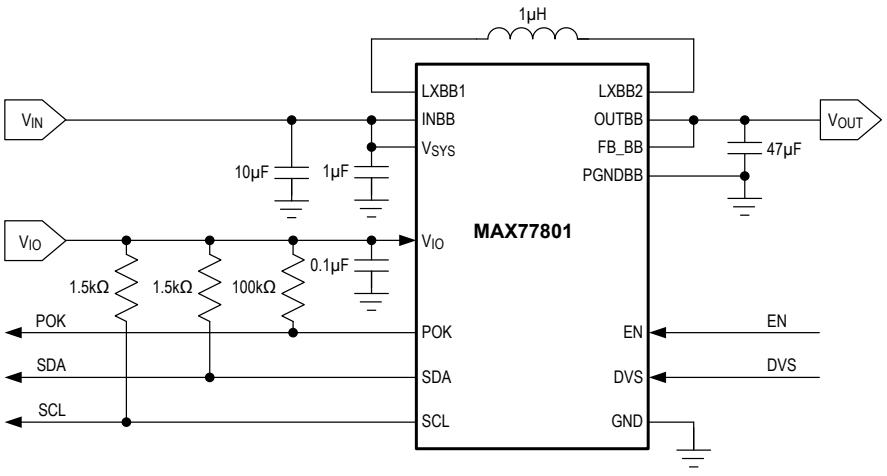
Applications

- Smartphones and Tablets
- Battery-Powered Applications

Benefits and Features

- 2A High-Efficiency Buck and Boost Operation Including Seamless Transition Between Buck and Boost Mode
- Flexibility Supports Various Designs
  - V_{OUT} Range from 2.60V to 4.1875V with 12.5mV Step
  - High-Speed (Up to 3.4MHz) I²C Serial Interface
- Low Quiescent Current, High Efficiency, and Dynamic Voltage Scaling Enable System to Be More Efficient
  - DVS Input
  - Up to 97% of Peak Efficiency
  - 55µA Quiescent Current
- High Switching Frequency and Small Package Reduce Solution Size
  - 2.5MHz Switching Frequency
  - Available in WLP and TQFN Packages
- Safety Features Enhance Device and System Reliability
  - POK Output
  - Soft-Start
  - True Shutdown™
  - Thermal Shutdown and Short-Circuit Protection

Typical Application Circuit



Ordering Information ***appears at end of data sheet.***

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Absolute Maximum Ratings

SYS, V_{IO} to GND ..... -0.3V to +6.0V
INBB, OUTBB to PGNDBB ..... -0.3V to +6.0V
PGNDBB to GND ..... -0.3V to +0.3V
SCL, SDA to GND ..... -0.3V to (V_{IO} + 0.3V)
EN, DVS, POK to GND ..... -0.3V to (V_{SYS} + 0.3V)
FB_BB to GND ..... -0.3V to (V_{OUTBB} + 0.3V)
LXBB1 to PGNDBB ..... -0.3V to (V_{INBB} + 0.3V)
LXBB2 to PGNDBB ..... -0.3V to (V_{OUTBB} + 0.3V)
LXBB1/LXBB2 Continuous RMS Current (Note 1) 3.3A
Operating Temperature Range ..... -40°C to +85°C
Junction Temperature ..... +150°C
Storage Temperature Range ..... -65°C to +150°C
Soldering Temperature (reflow) ..... +260°C

Note 1: LXBB1/LXBB2 node has internal clamp diodes to PGNDBB and INBB. Applications that give forward bias to these diodes should ensure that the total power loss does not exceed the power dissipation limit of IC package.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Thermal Characteristics (Note 2)

Junction-to-Ambient Thermal Resistance (θ_{JA})
20-Bump WLP ..... 55.49°C/W
20-Pin TQFN ..... 39°C/W

Note 2: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to **www.maximintegrated.com/thermal-tutorial**.

Buck-Boost Electrical Characteristics

(V_{SYS} = V_{INBB} = +3.8V, V_{FB_BB} = V_{OUTBB} = +3.3V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
GENERAL						
Input Voltage Range	V_{INBB}		2.3		5.5	V
Shutdown Supply Current	I_{SHDN_25C}	EN = low, T_A = +25°C		0.1		µA
	I_{SHDN_85C}	EN = low, T_A = +85°C		1		
Input Supply Current	I_{Q_SKIP}	SKIP mode, no switching		55	70	µA
	I_{Q_PWM}	FPWM mode, no load		6		mA
Active Discharge Resistance	R_{DISCHG}			100		Ω
Thermal Shutdown	T_{SHDN}	Rising, 20°C hysteresis		+165		°C
H-BRIDGE						
Output Voltage Range	V_{OUT}	I²C programmable (12.5mV step)	2.60		4.1875	V
Default Output Voltage		VOUT_DVS_L[6:0] = 0x38		3.3		V
		VOUT_DVS_H[6:0] = 0x40, MAX77801EWP only		3.4		
		VOUT_DVS_H[6:0] = 0x5C, MAX77801ETP only		3.75		
Output Voltage Accuracy	V_{OUT_ACC1}	PWM mode, BB_VOUT_DVS_x[6:0] = 0x40, no load	-1.0		+1.0	%
	V_{OUT_ACC2}	SKIP mode, BB_VOUT_DVS_x[6:0] = 0x40, no load, T_A = +25°C	-1.0		+4.5	

Buck-Boost Electrical Characteristics (continued)

(V_{SYS} = V_{INBB} = +3.8V, V_{FB_BB} = V_{OUTBB} = +3.3V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Line Regulation		V_{INBB} = 2.3V to 5.5V		0.200		%/V
Load Regulation		(Note 4)		0.125		%/A
Line Transient Response	V_{OS1} V_{US1}	I_{OUT} = 1.5A, V_{INB} changes from 3.4V to 2.9V in 25µs (20mV/µs), L = 1µH, C_{OUT_NOM} = 47µF (Note 4)		50		mV
Load Transient Response	V_{OS2} V_{US2}	V_{INBB} = 3.4V, I_{OUT} changes from 10mA to 1.5A in 15µs, L = 1µH, C_{OUT_NOM} = 47µF (Note 4)		50		mV
Output Voltage Ramp-Up Slew Rate		BB_RU_SR = 0		12.5		mV/µs
		BB_RU_SR = 1		25		
Output Voltage Ramp-down Slew Rate		BB_RD_SR = 0		3.125		mV/µs
		BB_RD_SR = 1		6.25		
Typical Load Efficiency	ηIOUT_TYP	I_{OUT} = 100mA, V_{INBB} = 3.6V (Note 4)		95		%
Peak Efficiency	ηPK	(Note 4)		97		%
Maximum Output Current	$I_{OUT(MAX)}$	2.8V ≤ V_{INBB} ≤ 5.5V	2000			mA
	$I_{OUT(MAX)}$	2.3V ≤ V_{INBB} < 2.8V	1000			
LXBB1/2 Current Limit	I_{LIM_LXBB}		3.70	4.70	5.70	A
High-Side PMOS ON Resistance	R_{DSON} (PMOS)	I_{LXBB} = 100mA per switch, WLP		40		mΩ
		I_{LXBB} = 100mA per switch, TQFN		50		
Low-Side NMOS ON Resistance	R_{DSON} (NMOS)	I_{LXBB} = 100mA per switch, WLP		55		mΩ
		I_{LXBB} = 100mA per switch, TQFN		65		
Switching Frequency	f_{SW}	PWM mode, T_A = +25°C	2.25	2.50	2.75	MHz
Turn-On Delay Time	t_{ON_DLY}	From EN asserting to LXBB switching with bias ON		100		µs
Soft-Start Time	t_{SS}	I_{OUT} = 10mA		120		µs
Minimum Effective Output Capacitance	$C_{EFF(MIN)}$	0A < I_{OUT} < 2000mA		16		µF
LXBB1, LXBB2 Leakage Current	I_{LK_25}	$V_{LXBB1/2}$ = 0V or 5.5V, V_{OUTBB} = 5.5V, V_{SYS} = V_{INBB} = 5.5V, T_A = +25°C		0.1	1	µA
	I_{LK_85}	$V_{LXBB1/2}$ = 0V or 5.5V, V_{OUTBB} = 5.5V, V_{SYS} = V_{INBB} = 5.5V, T_A = +85°C		0.2		
POWER-OK COMPARATOR						
Output POK Trip Level		Rising threshold		80		%
		Falling threshold		75		%

Buck-Boost Electrical Characteristics (continued)

(V_{SYS} = V_{INBB} = +3.8V, V_{FB_BB} = V_{OUTBB} = +3.3V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
V_{SYS} UNDERVOLTAGE LOCKOUT						
V_{SYS} Undervoltage Lockout Threshold	V_{UVLO_R}	V_{SYS} rising	2.375	2.50	2.625	V
	V_{UVLO_F}	V_{SYS} falling (default)		2.05		V
LOGIC AND CONTROL INPUTS						
Input Low Level	V_{IL}	EN, DVS, V_{SYS} ≤ 4.5V, T_A = +25°C			0.4	V
Input High Level	V_{IH}	EN, DVS, V_{SYS} ≤ 4.5V, T_A = +25°C	1.2			V
POK Output Low Voltage	V_{OL}	I_{SINK} = 1mA			0.4	V
POK Output High Leakage	I_{OZH_25C}	T_A = +25°C	-1		+1	µA
	I_{OZH_85C}	T_A = +85°C		0.1		µA
INTERNAL PULLDOWN RESISTANCE						
EN, DVS	RPD	Pulldown resistor to GND	400	800	1600	kΩ

I²C Electrical Characteristics

(V_{SYS} = 3.8V, V_{IO} = 1.8V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
V_{IO} Voltage Range	V_{IO}		1.7		3.6	V
SDA AND SCL I/O STAGES						
SCL, SDA Input High Voltage	V_{IH}		0.7 x V_{IO}			V
SCL, SDA Input Low Voltage	V_{IL}				0.3 x V_{IO}	V
SCL, SDA Input Hysteresis	V_{HYS}			0.05 x V_{IO}		V
SCL, SDA Input Current	I_I	V_{IO} = 3.8V	-10		+10	µA
SDA Output low Voltage	V_{OL}	I_{SINK} = 20mA			0.4	V
SCL, SDA Input Capacitance	C_I			10		pF
Output Fall Time from V_{IO} to 0.3 x V_{IO}	t_{OF}				120	ns
I²C-COMPATIBLE INTERFACE TIMING (STANDARD, FAST, AND FAST MODE PLUS) (Note 4)						
Clock Frequency	f_{SCL}				1000	kHz
Hold Time (REPEATED) START Condition	$t_{HD;STA}$		0.26			µs
SCL low Period	t_{low}		0.5			µs
SCL high Period	t_{high}		0.26			µs
Setup Time REPEATED START Condition	t_{SU_STA}		0.26			µs

I²C Electrical Characteristics (continued)

(V_{SYS} = 3.8V, V_{IO} = 1.8V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
DATA Hold Time	t_{HD_DAT}		0			µs
DATA Setup Time	t_{SU_DAT}		50			ns
Setup Time for STOP Condition	t_{SU_STO}		0.26			µs
Bus-Free Time Between STOP and START	t_{BUF}		0.5			µs
Capacitive Load for Each Bus Line	C_B				550	pF
Maximum Pulse Width of Spikes That Must Be Suppressed by the Input Filter				50		ns
I²C-COMPATIBLE INTERFACE TIMING (HIGH-SPEED MODE, C_B = 100pF) (Note 4)						
Clock Frequency	f_{SCL}				3.4	MHz
Set-Up Time REPEATED START Condition	t_{SU_STA}		160			ns
Hold Time (REPEATED) START Condition	t_{HD_STA}		160			ns
CLK Low Period	t_{low}		160			ns
CLK High Period	t_{high}		60			ns
DATA Setup Time	t_{SU_DAT}		10			ns
DATA Hold Time	t_{HD_DAT}			35		ns
SCL Rise Time (Note 4)	t_{RCL}	T_A = +25°C	10		40	ns
Rise Time of SCL Signal After REPEATED START Condition and After Acknowledge Bit	t_{RCL1}	T_A = +25°C	10		80	ns
SCL Fall Time	t_{FCL}	T_A = +25°C	10		40	ns
SDA Rise Time	t_{RDA}	T_A = +25°C			80	ns
SDA Fall Time	t_{FDA}	T_A = +25°C			80	ns
Setup Time for STOP Condition	t_{SU_STO}		160			ns
Bus Capacitance	C_B				100	pF
Maximum Pulse Width of Spikes That Must Be Suppressed by the Input Filter				10		ns

I²C Electrical Characteristics (continued)

(V_{SYS} = 3.8V, V_{IO} = 1.8V, T_A = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
I²C-COMPATIBLE INTERFACE TIMING (HIGH-SPEED MODE, C_B = 400pF) (Note 4)						
Clock Frequency	f_{SCL}				1.7	MHz
Setup Time REPEATED START Condition	t_{SU_STA}		160			ns
Hold Time (REPEATED) START Condition	t_{HD_STA}		160			ns
SCL Low Period	t_{low}		320			ns
SCL High Period	t_{high}		120			ns
DATA Setup Time	t_{SU_DAT}		10			ns
DATA Hold Time	t_{HD_DAT}			75		ns
SCL Rise Time	t_{RCL}	T_A = +25°C	20		80	ns
Rise Time of SCL Signal After REPEATED START Condition and After Acknowledge Bit	t_{RCL1}	T_A = +25°C	20		160	ns
SCL Fall Time	t_{FCL}	T_A = +25°C	20		80	ns
SDA Rise Time	t_{RDA}	T_A = +25°C			160	ns
SDA Fall Time	t_{FDA}	T_A = +25°C			160	ns
Setup Time for STOP Condition	t_{SU_STO}		160			ns
Bus Capacitance	C_B				400	pF
Maximum Pulse Width of Spikes That Must Be Suppressed by the Input Filter	t_{SP}			10		ns

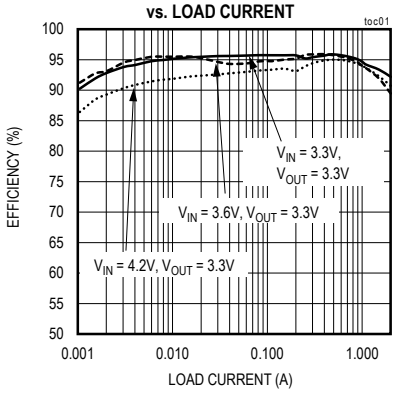
Note 3: Limits are 100% production tested at T_A = +25°C. Limits over the operating temperature range are guaranteed through correlation using statistical quality control methods.

Note 4: Guaranteed by design. Not production tested.

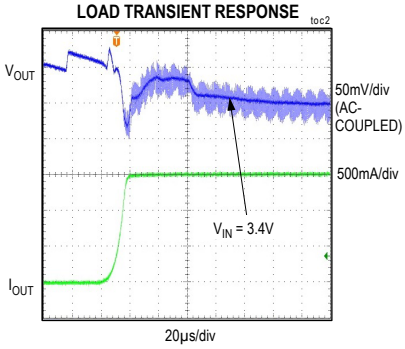
Typical Operating Characteristics

(V_{SYS} = V_{INBB} = +3.8V , V_{FB_BB} = V_{OUTBB} = +3.3V, T_A = +25°C.)

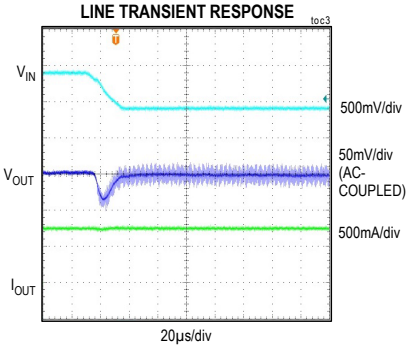
EFFICIENCY vs. LOAD CURRENT



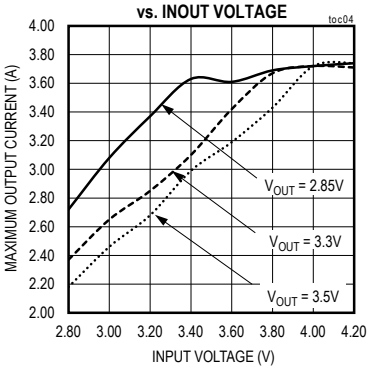
LOAD TRANSIENT RESPONSE



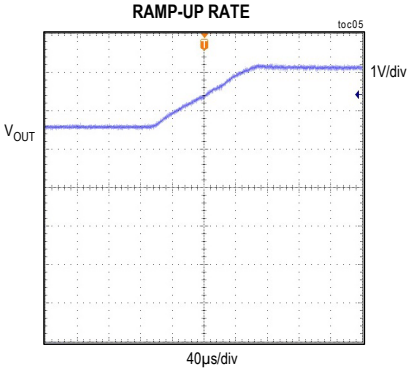
LINE TRANSIENT RESPONSE



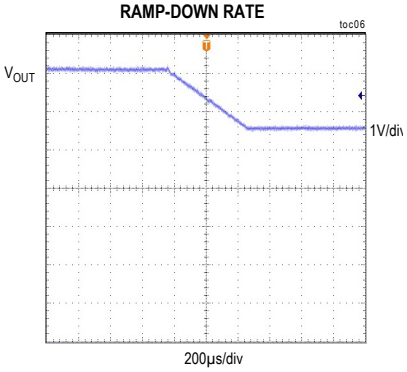
MAXIMUM OUTPUT CURRENT vs. INOUT VOLTAGE



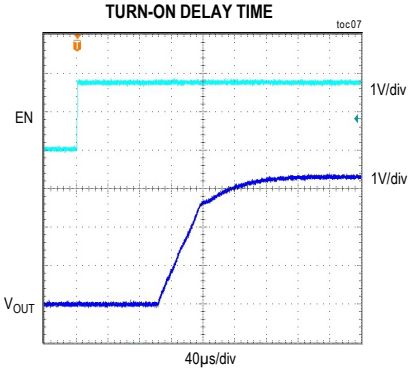
OUTPUT VOLTAGE RAMP-UP RATE



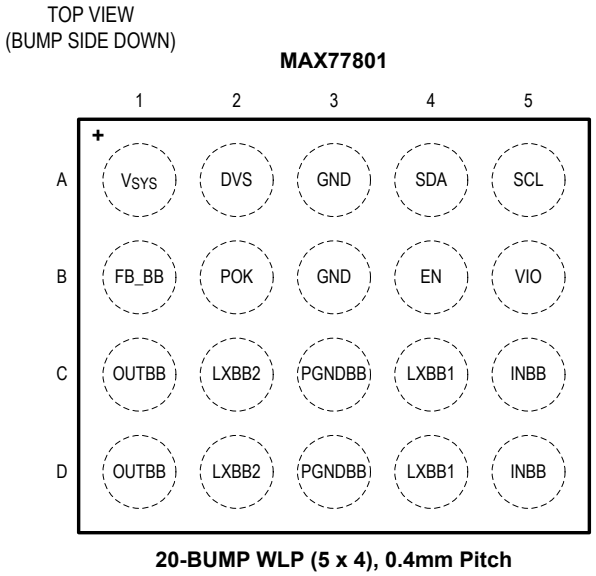
OUTPUT VOLTAGE RAMP-DOWN RATE



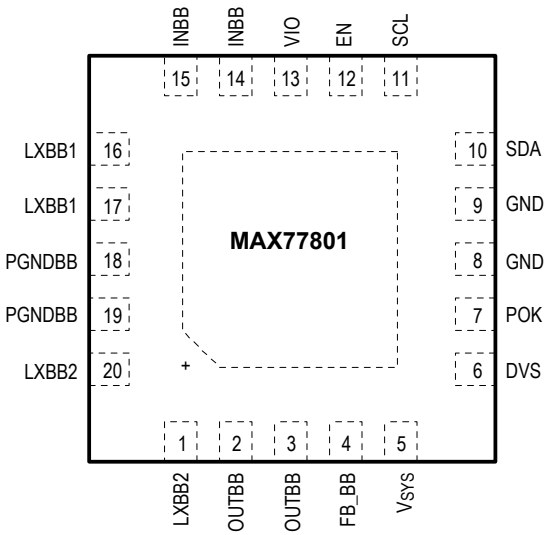
TURN-ON DELAY TIME



Bump/Pin Configurations



20-BUMP WLP (5 x 4), 0.4mm Pitch



20-PIN TQFN

Bump/Pin Description

20-BUMP WLP	20-PIN TQFN	NAME	FUNCTION
A1	5	V_{SYS}	System (Battery) Voltage Input. Bypass to GND with a 1µF capacitor.
A2	6	DVS	Dynamic Voltage Scaling Logic Input. If not in use, then it must be connected to GND.
A3, B3	8, 9	GND	Ground. Star-Ground Connection to System GND
A4	10	SDA	I^2C Data I/O (High Impedance in Off State). A 1.5kΩ~2.2kΩ of pullup resistor to V_{IO} is required.
A5	11	SCL	I^2C Clock Input (High Impedance in Off State). A 1.5kΩ~2.2kΩ of pullup resistor to V_{IO} is required.
B1	4	FB_BB	Buck-Boost Output Voltage Feedback
B2	7	POK	Power OK. Open-drain output asserted after buck-boost output reaches to 80% of output voltage. Polarity is factory selectable option. Active high by default.
B4	12	EN	Active-High, Buck-Boost External Enable Input. An 800kΩ internal pulldown resistance to the GND. If this pin is not used, leave it floating.
B5	13	V_{IO}	I^2C Supply Voltage Input. Bypass to GND with a 0.1µF capacitor. If not in use, connect to GND.
C1, D1	2, 3	OUTBB	Buck-Boost Output
C2, D2	1, 20	LXBB2	Buck-Boost Switching Node 2
C3, D3	18, 19	PGNDBB	Buck-Boost Power Ground. Star-ground connection to system GND.
C4, D4	16, 17	LXBB1	Buck-Boost Switching Node 1
C5, D5	14, 15	INBB	Buck-Boost Input. Bypass to PGNDBB with a 10µF capacitor.

Detailed Description

Chip Enable (EN)

When EN pin goes high, the MAX77801 turns on the internal bias circuitry, which typically takes 85µs to settle. As soon as the bias is ready, buck-boost regulator is enabled. Once V_{IO} is supplied, then all user registers are accessible through I²C. When EN pin is pulled low, the MAX77801 goes into shutdown mode. This event also resets all type-O registers to their POR default values.

Immediate Turn-Off Events

The following events initiate immediate turn-off:

- Thermal protection (T_J > +165°C)
- V_{SYS} < $V_{SYS\ UVLO}$ falling threshold (V_{UVLO_F})
- Overcurrent protection

The events in this category disable buck-boost until the hazardous condition come back to normal conditions.

Regulator Enable Control

Buck-boost has GPIO enable pin EN as well as I²C enable bit. As shown in the Table 1, the regulator should be enabled by EN and then it can be enabled or disabled by I²C control bit (AND logic) until EN remains in high.

Dynamic Voltage Scaling (DVS)

Buck-boost includes DVS feature that allows output voltage to change dynamically. The buck-boost output voltages are selected by DVS. When EN pin is asserted, the status of DVS pin is latched until completing soft-start so that changes on DVS are ignored. After soft-start is done, internal logic sets V_{OUT} based on DVS input.

Buck-boost regulator supports a programmable slew-rate control feature when increasing and decreasing the output voltage. The ramp-up slew rate can be set to 12.5mV/µs or 25mV/µs through BB_RU_SR bit. Also, the ramp-down slew rate can be set to 3.125mV/µs or 6.25mV/µs through BB_RD_SR bit.

Power-OK (POK) Indicator

Buck-boost has an open-drain output that is asserted after the output voltage reaches 90%. The polarity of POK output is factory programmable option. It is active high by default.

Table 1. Enable Control Logic Truth Table

EN	BB_EN BIT	OPERATING MODE
low	x	Device off
high	0	Disable output
high	1 (default)	Enable output

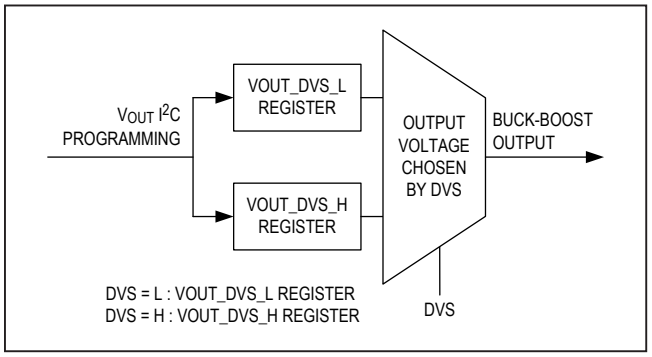


Figure 1. DVS Functional Block Diagram

Buck-Boost Regulator

When EN pin goes high, the MAX77801 turns on the internal bias circuitry, which typically takes 85µs to settle. As soon as the bias is ready, buck-boost regulator is enabled. Once V_{IO} is supplied, then all user registers are accessible through I²C. When EN pin is pulled low, the MAX77801 goes into shutdown mode. This event also resets all type-O registers to their POR default values.

H-Bridge Controller

H-bridge architecture operates at 2.5MHz fixed frequency with a pulse width modulated (PWM), current-mode control scheme. This topology is in a cascade of a boost regulator and a buck regulator using a single inductor and output capacitor. Buck, buck-boost, and boost stages are 100% synchronous for highest efficiency in portable applications.

There are three phases implemented with the H-bridge switch topology, as shown in Figure 3:

- Φ1 switch period (Phase 1: HS1 = ON, LS2 = ON) stores energy in the inductor, ramping up the inductor current at a rate proportional to the input voltage divided by inductance, $V_{INBB/L}$.
- Φ2 switch period (Phase 2: HS1 = ON, HS2 = ON) ramps the inductor current up or down, depending on the differential voltage across the inductor, divided by inductance; $\pm(V_{INBB} - V_{OUTBB})/L$.
- Φ3 switch period (Phase 3: LS1 = ON, HS2 = ON) ramps down the inductor current at a rate proportional to the output voltage divided by inductance, $-V_{OUTBB/L}$.

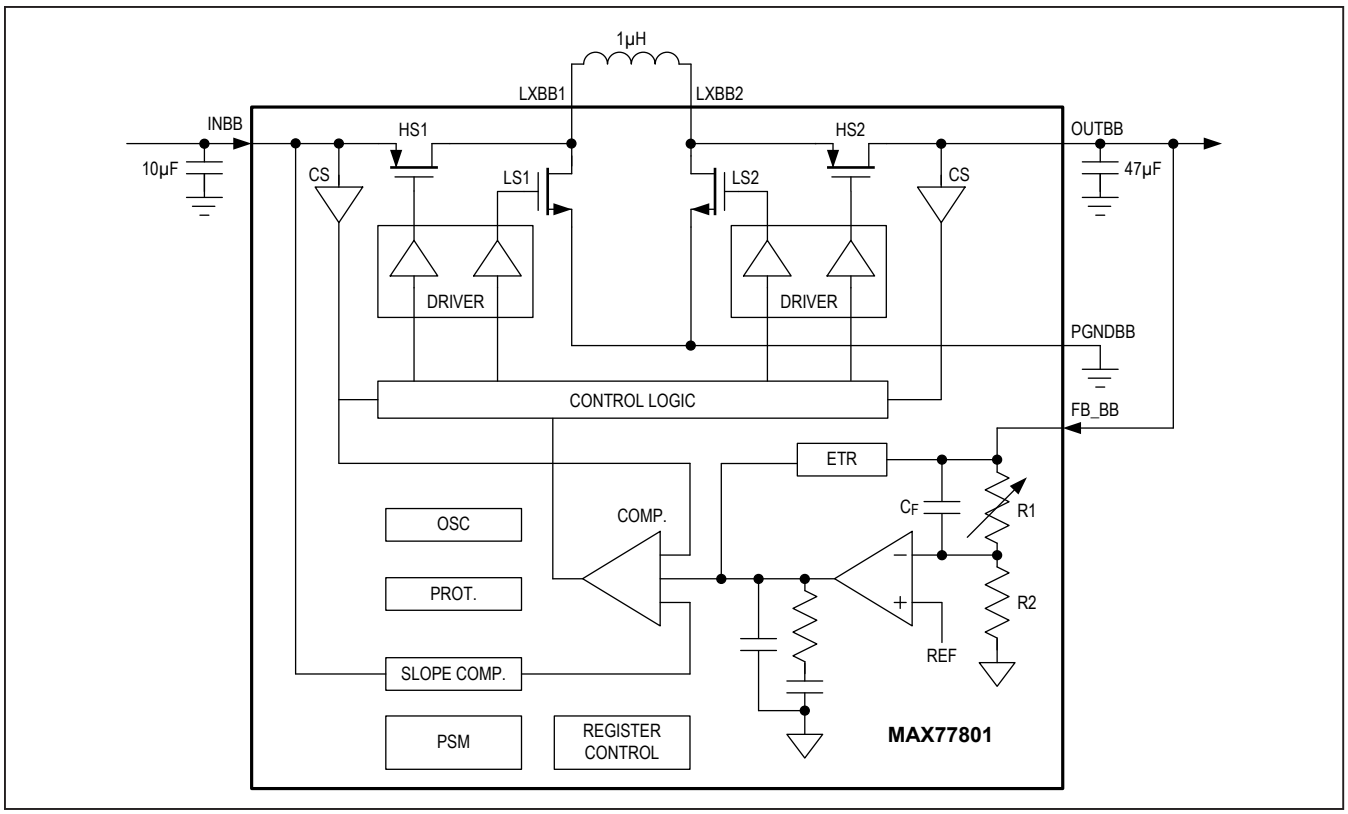


Figure 2. Buck-Boost Block Diagram

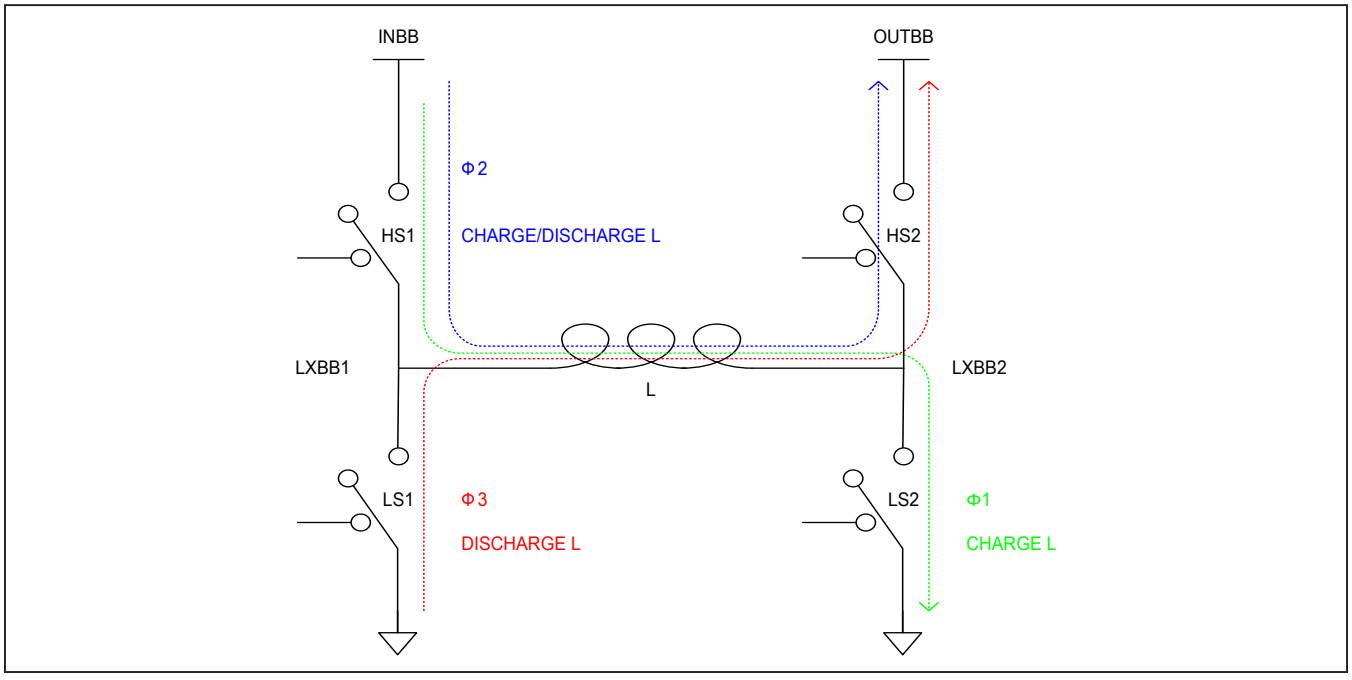


Figure 3. Buck-Boost Switching Intervals

2-phase buck topology is utilized when $V_{INBB} > V_{OUTBB}$. A switching cycle is completed in one clock period. Switch period Φ2 is followed by switch period Φ3, resulting in an inductor current waveform similar to Figure 4.

2-phase boost topology is utilized when $V_{INBB} < V_{OUTBB}$. A switching cycle is completed in one clock period. Switch period Φ1 is followed by switch period Φ2, resulting in an inductor current waveform similar to Figure 5.

Output Voltage Slew-rate Control

Buck-boost regulator supports programmable slew-rate control feature when increasing and decreasing the output voltage. The ramp-up slew-rate can be set to 12.5mV/µs or 25mV/µs through BB_RU_SR bit, while the ramp-down slew-rate is programmable to 3.125mV/µs or 6.25mV/µs through BB_RD_SR bit.

Output Active Discharge

Buck-boost provides an internal 100Ω resistor for output active discharge function. If the active discharge function is enabled (BB_AD = 1), the internal resistor discharges the energy stored in the output capacitor to PGNDBB whenever the regulator is disabled.

Either the regulator remains enabled or the active discharge function is disabled (BB_AD = 0), the internal resistor is disconnected from the output. If the active discharge function is disabled, the output voltage decays at a rate that is determined by the output capacitance and the load current when the regulator is turned off.

Inductor Selection

Buck-boost is optimized for a 1µH inductor. The lower the inductor DCR, the higher buck-boost efficiency is. Users need to trade off inductor size with DCR value and choose a suitable inductor for buck-boost.

Input Capacitor Selection

The input capacitor, C_{IN}, reduces the current peaks drawn from the battery or input power source and reduces switching noise in the device. The impedance of C_{IN} at the switching frequency should be kept very low. Ceramic capacitors with X5R or X7R dielectrics are highly recommended due to their small size, low ESR, and small temperature coefficients. For most applications, a 10µF capacitor is sufficient.

Output Capacitor Selection

The output capacitor, C_{OUT}, is required to keep the output voltage ripple small and to ensure regulation loop stability. C_{OUT} must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectric are highly recommended due to their small size, low ESR, and small temperature coefficients. For stable operation, buck-boost requires 16µF of minimum effective output capacitance. Considering DC bias characteristic of ceramic capacitors, a 47µF 6.3V capacitor is recommended for most of applications.

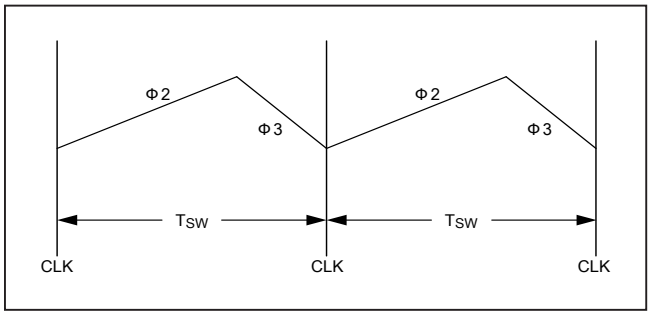


Figure 4. 2-Phase Buck Mode Switching Current Waveforms

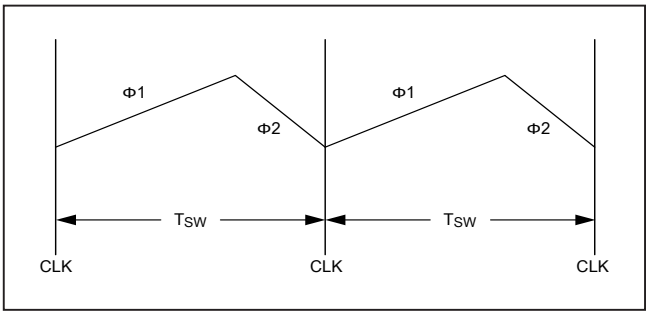


Figure 5. 2-Phase Boost Mode Switching Current Waveforms

Table 2. Suggested Inductors for Buck-Boost

MANUFACTURER	SERIES	NOMINAL INDUCTANCE (µH)	DC RESISTANCE (typ) (mΩ)	CURRENT RATING (A) -30% (ΔL/L)	CURRENT RATING (A) ΔT = -40°C RISE	DIMENSIONS L x W x H (mm)
TDK	TFM201610GHM-1R0MTAA	1.0	50	3.8	3.0	2.0 x 1.6 x 1.0
Coilcraft	XAL4020-102MEB	1.0	13	8.7	9.6	4.0 x 4.0 x 2.1

Serial Interface

I²C compatible 2-wire serial interface is used for regulator on/off control, setting output voltages, and other functions. See the *Register Map* section for details.

I²C serial bus consists of a bidirectional serial-data line (SDA) and a serial clock (SCL). I²C is an open-drain bus. SDA and SCL require pullup resistors (500Ω or greater). Optional 24Ω resistors in series with SDA and SCL help to protect the device inputs from high voltage spikes on the bus lines. Series resistors also minimize crosstalk and undershoot on bus lines.

System Configuration

I²C bus is a multimaster bus. The maximum number of devices that can attach to the bus is only limited by bus capacitance.

The figure above shows an example of a typical I²C system. A device on I²C bus that sends data to the bus in called a transmitter. A device that receives data from the bus is called a receiver. The device that initiates a data transfer and generates SCL clock signals to control the data transfer is the master. Any device that is being addressed by the master is considered a slave. When the MAX77801 I²C-compatible interface is operating, it is a slave on I²C bus, and it can be both a transmitter and a receiver, too.

Bit Transfer

One data bit is transferred for each SCL clock cycle. The data on SDA must remain stable during the high portion of SCL clock pulse. Changes in SDA while SCL is high are control signals (START and STOP conditions).

START and STOP Conditions

When I²C serial interface is inactive, SDA and SCL idle high. A master device initiates communication by issuing a START (S) condition. A START condition is a high-to-low transition on SDA with SCL high. A STOP (P) condition is a low-to-high transition on SDA, while SCL is high.

A START condition from the master signals the beginning of a transmission to the MAX77801. The master terminates transmission by issuing a NOT ACKNOWLEDGE (nA) followed by a STOP condition.

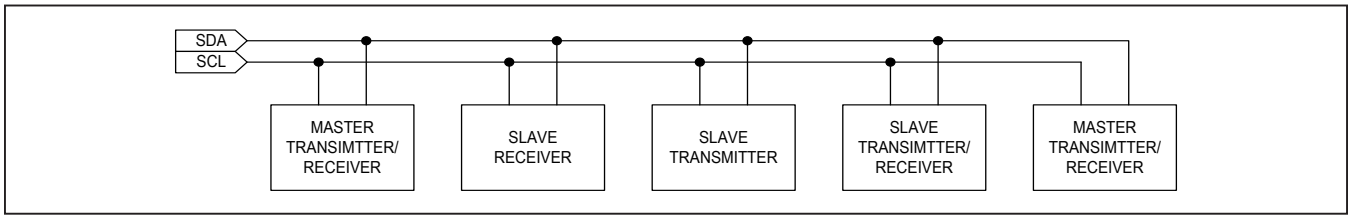


Figure 6. Functional Logic Diagram for Communications Controller

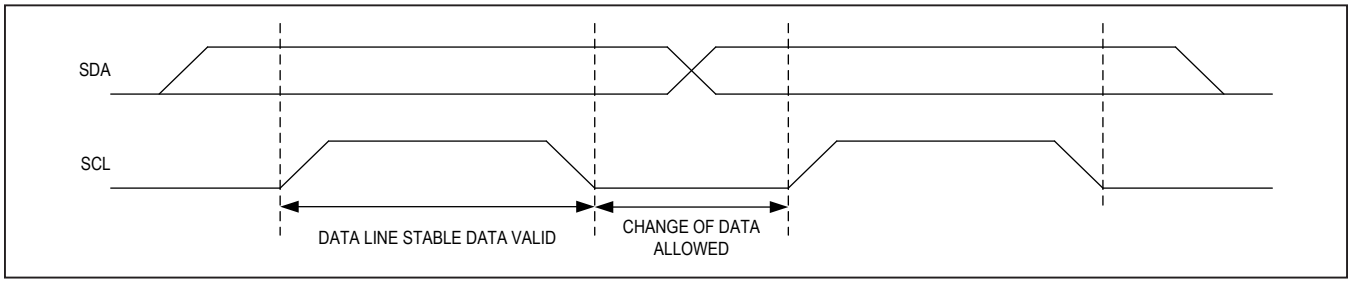


Figure 7. I²C Bit Transfer

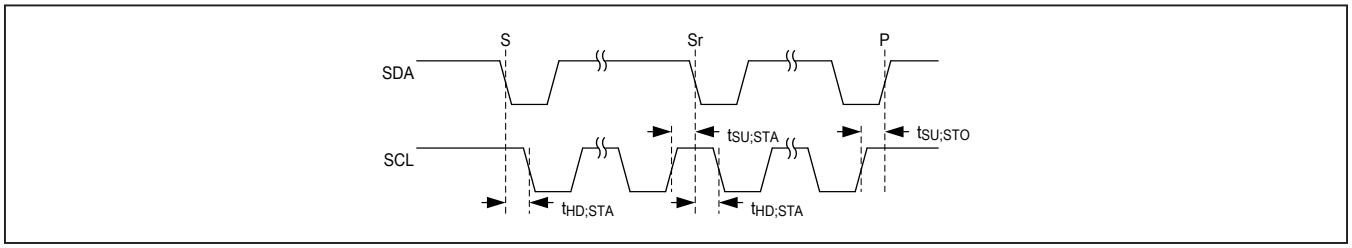


Figure 8. START and STOP Conditions

STOP condition frees the bus. To issue a series of commands to the slave, the master may issue REPEATED START (Sr) commands instead of a STOP command in order to maintain control of the bus. In general, a REPEATED START command is functionally equivalent to a regular START command.

When a STOP condition or incorrect address is detected, the MAX77801 internally disconnects SCL from I2C serial interface until the next START condition, minimizing digital noise and feedthrough.

Acknowledge

Both I2C bus master and MAX77801 (slave) generate acknowledge bits when receiving data. The acknowledge bit is the last bit of each nine bit data packet. To generate an ACKNOWLEDGE (A), the receiving device must pull SDA low before the rising edge of the acknowledge-related clock pulse (ninth pulse) and keep it low during the high period of the clock pulse. To generate a NOT ACKNOWLEDGE, the receiving device allows SDA to be pulled high before the rising edge of the acknowledge-related clock pulse and leaves it high during the high period of the clock pulse.

Monitoring the acknowledge bits allows for detection of unsuccessful data transfers. An unsuccessful data transfer occurs if a receiving device is busy or if a system fault has occurred. In the event of an unsuccessful data transfer, the bus master should reattempt communication at a later time.

Slave Address

The I2C slave address of the MAX77801 is shown in Table 3.

Clock Stretching

In general, the clock signal generation for the I2C bus is the responsibility of the master device. I2C specification allows slow slave devices to alter the clock signal by holding down the clock line. The process in which a slave device holds down the clock line is typically called clock stretching. The MAX77801 does not use any form of clock stretching to hold down the clock line.

General Call Address

The MAX77801 does not implement the I2C specification called general call address. If the MAX77801 sees a general call address (00000000b), it does not issue an ACKNOWLEDGE.

Communication Speed

The MAX77801 provides I2C 3.0-compatible (3.4MHz) serial interface.

- I2C revision 3-compatible serial communications channel
  - 0Hz to 100kHz (standard mode)
  - 0Hz to 400kHz (fast mode)
  - 0Hz to 1MHz (fast mode plus)
  - 0Hz to 3.4MHz (high-speed mode)
- Does not utilize I2C clock stretching

Operating in standard mode, fast mode, and fast mode plus does not require any special protocols. The main consideration when changing the bus speed through this range is the combination of the bus capacitance and pullup resistors. Higher time constants created by the bus capacitance and pullup resistance (C x R) slow the bus operation. Therefore, when increasing bus speeds, the pullup resistance must be decreased to maintain a reasonable time constant. Refer to the *Pullup Resistor Sizing* section of I2C revision 3.0 specification for detailed guidance on the pullup resistor selection. In general, for bus capacitances of 200pF, a 100kHz bus needs 5.6kΩ pullup resistors, a 400kHz bus needs about a 1.5kΩ pullup resistors, and a 1MHz bus needs 680Ω pullup resistors. Note that the pullup resistor is dissipating power when the open-drain bus is low. The lower the value of the pullup resistor, the higher the power dissipation (V2/R).

Table 3. I2C Slave Address

SLAVE ADDRESS (7 bit)	SLAVE ADDRESS (Write)	SLAVE ADDRESS (Read)
001 1000	0x30 (0011 0000)	0x31 (0011 0001)

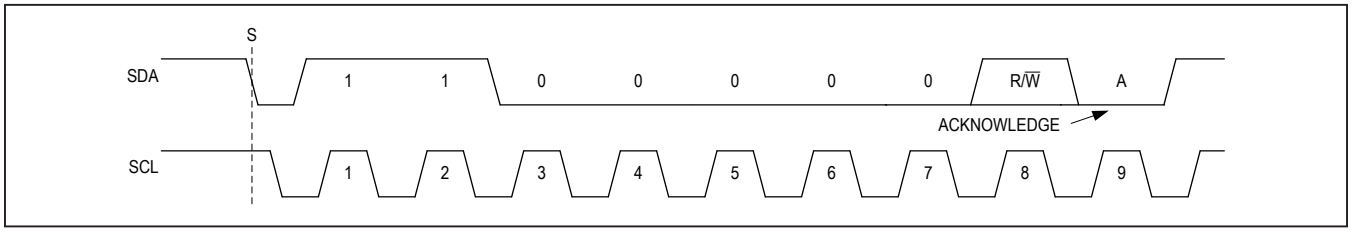


Figure 9. Slave Address Byte Example

Operating in high-speed mode requires some special considerations. For the full list of considerations, refer to the I2C 3.0 specification. The major considerations with respect to the MAX77801 are:

- I2C bus master uses current source pullups to shorten the signal rise times.
- I2C slave must use a different set of input filters on its SDA and SCL lines to accommodate for the higher bus speed.
- The communication protocols need to utilize the high-speed master code.

At power-up and after each STOP condition, the MAX77801 inputs filters are set for standard mode, fast mode, or fast mode plus (i.e., 0Hz to 1MHz). To switch the input filters for high-speed mode, use the high-speed master code protocols that are described in *Communication Protocols* section.

Communication Protocols

The MAX77801 supports both writing and reading from its registers. The following sections show the I2C communication protocols for each functional block. The power block uses the same communications protocols.

Writing to a Single Register

Figure 10 shows the protocol for I2C master device to write one byte of data to the MAX77801. This protocol is the same as SMBus specification's write byte protocol.

The write byte protocol is as follows:

1. The master sends a START command.
2. The master sends the 7-bit slave address followed by a write bit (R/W 0).
3. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
4. The master sends an 8-bit register pointer.
5. The slave acknowledges the register pointer.
6. The master sends a data byte.
7. The slave acknowledges the data byte. At the rising edge of SCL, the data byte will be loaded into its target register and the data becomes active.
8. The master sends a STOP condition or a REPEATED START condition. Issuing a STOP ensures that the bus input filters are set for 1MHz or slower operation. Issuing a REPEATED START leaves the bus input filters in their current state.

Writing to a Sequential Register

Figure 11 shows the protocol for writing to a sequential registers. This protocol is similar to the write byte protocol, except the master continues to write after it receives the first byte of data. When the master is done writing, it issues a STOP or REPEATED START. The writing to sequential registers protocol is as follows:

1. The master sends a START command.
2. The master sends the 7-bit slave address followed by a write bit (R/$\overline{W}$ = 0).
3. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
4. The master sends an 8-bit register pointer.
5. The slave acknowledges the register pointer.
6. The master sends a data byte.
7. The slave acknowledges the data byte. At the rising edge of SCL, the data byte will be loaded into its target register and the data becomes active.
8. Steps 6 to 7 are repeated as many times as the master requires. During the last acknowledge related clock pulse, the slave can issue an ACKNOWLEDGE.
9. The master sends a STOP condition or a REPEATED START condition. Issuing a STOP ensures that the bus input filters are set for 1MHz or slower operation. Issuing a REPEATED START leaves the bus input filters in their current state.

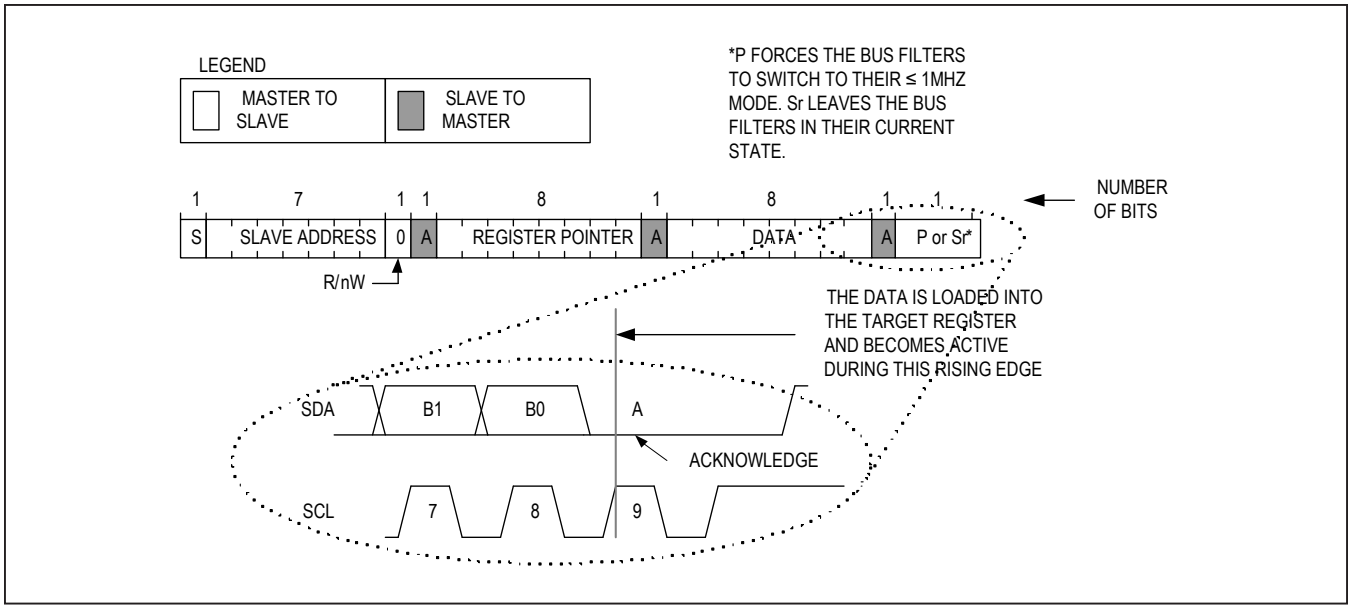


Figure 10. Writing to a Single Register with Write Byte Protocol

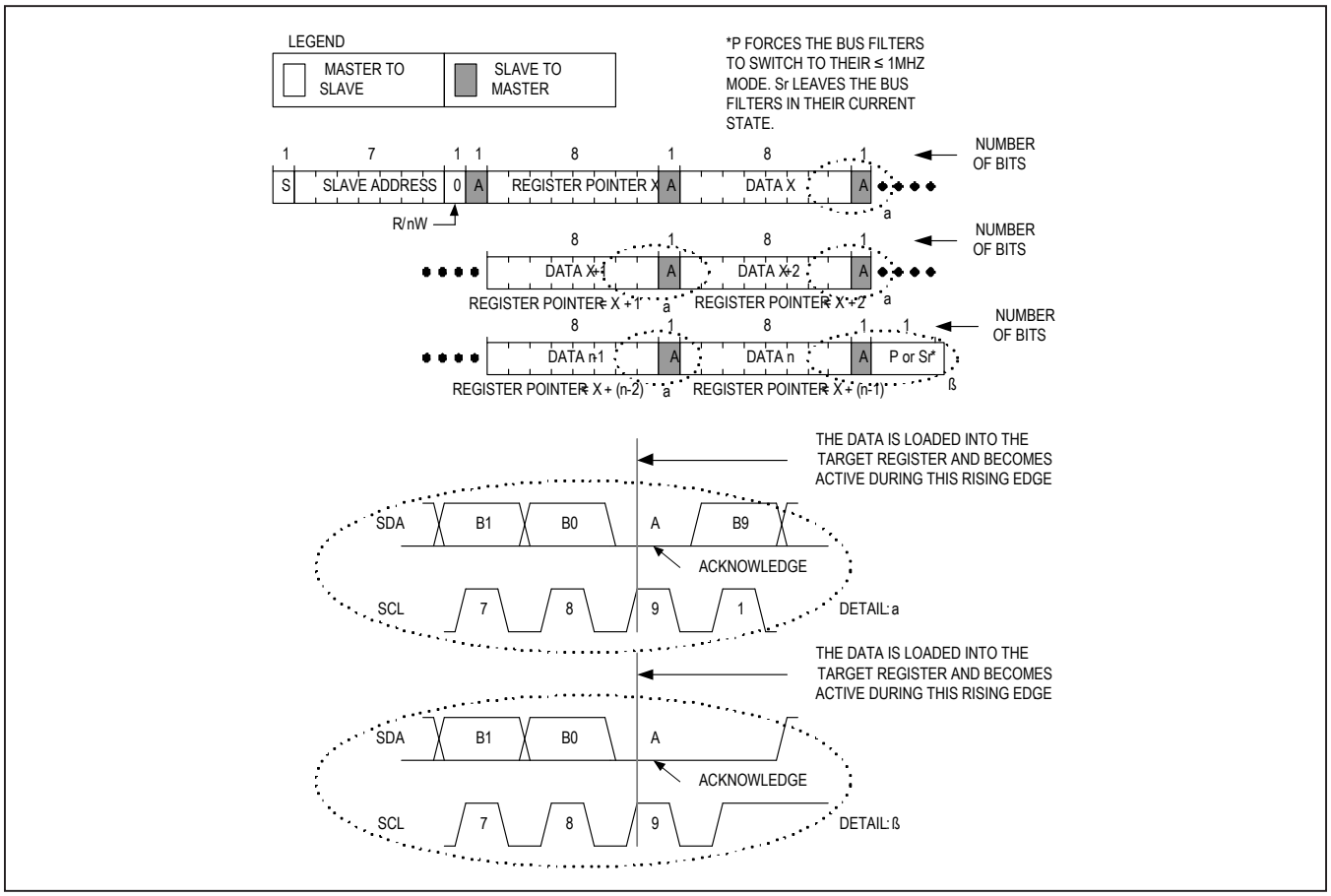


Figure 11. Writing to Sequential Registers X to N

Writing Multiple Bytes Using Register-Data Pairs

Figure 12 shows the protocol for I2C master device to write multiple bytes to the MAX77801 using register-data pairs. This protocol allows I2C master device to address the slave only once and then send data to multiple registers in a random order. Registers can be written continuously until the master issues a STOP condition.

The multiple byte register-data pair protocol is as follows:

1. The master sends a START command.
2. The master sends the 7-bit slave address followed by a write bit.
3. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
4. The master sends an 8-bit register pointer.
5. The slave acknowledges the register pointer.
6. The master sends a data byte.
7. The slave acknowledges the data byte. At the rising edge of SCL, the data byte will be loaded into its target register and the data becomes active.
8. Steps 4 to 7 are repeated as many times as the master requires.
9. The master sends a STOP condition.

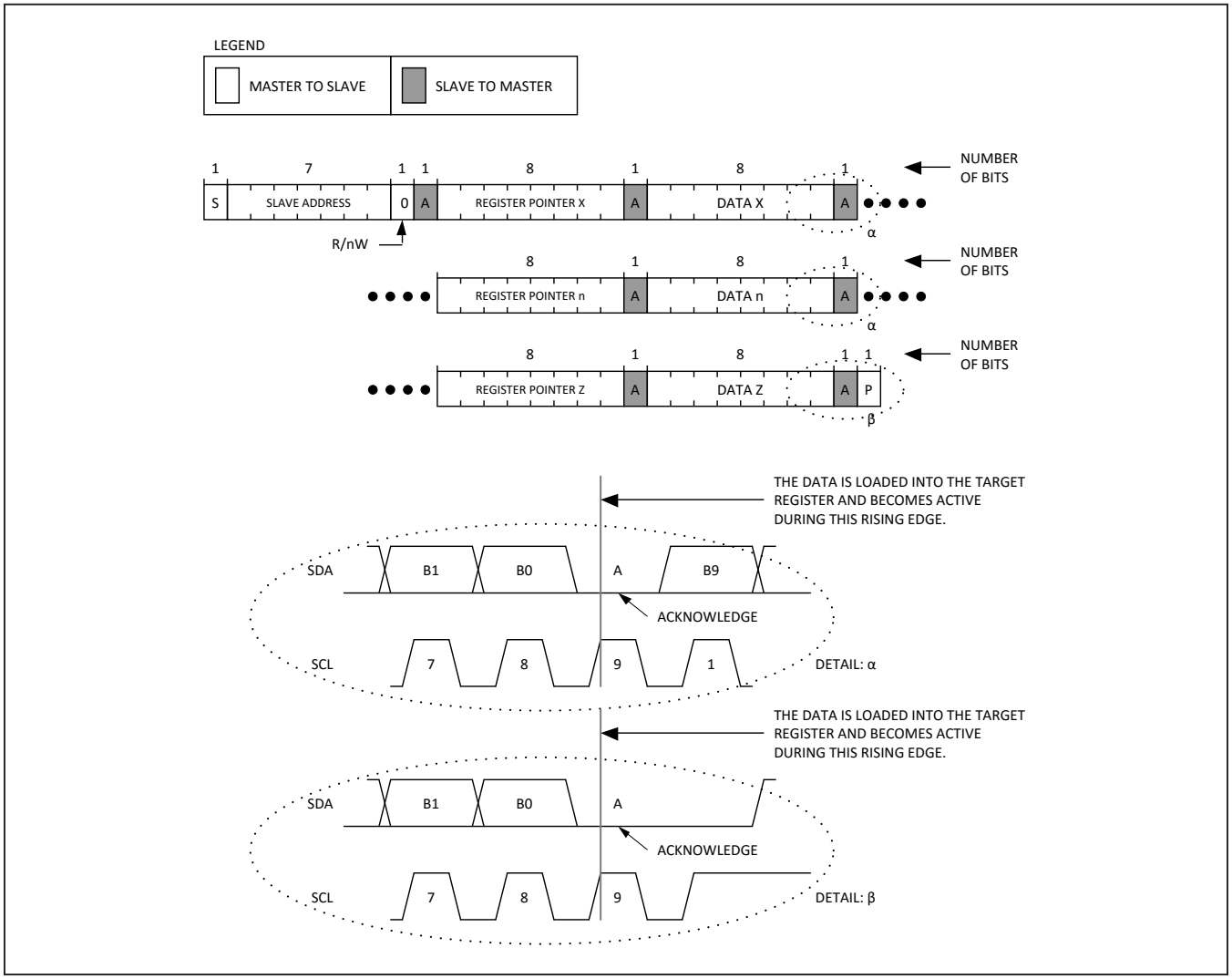


Figure 12. Writing to Multiple Registers with Multiple Byte Register-Data Pairs Protocol

Reading from a Single Register

I2C master device reads one byte of data to the MAX77801. This protocol is the same as SMBus specification's read byte protocol.

The read byte protocol is as follows:

1. The master sends a START command.
2. The master sends the 7-bit slave address followed by a write bit (R/$\overline{W}$ = 0).
3. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
4. The master sends an 8-bit register pointer.
5. The slave acknowledges the register pointer.
6. The master sends a REPEATED START command.
7. The master sends the 7-bit slave address followed by a read bit (R/$\overline{W}$ = 1).
8. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
9. The addressed slave places 8 bits of data on the bus from the location specified by the register pointer.
10. The master issues a NOT-ACKNOWLEDGE.
11. The master sends a STOP condition or a REPEATED START condition. Issuing a STOP ensures that the bus input filters are set for 1MHz or slower operation. Issuing a REPEATED START leaves the bus input filters in their current state.

Reading from a Sequential Register

Figure 13 shows the protocol for reading from sequential registers. This protocol is similar to the read byte protocol except the master issues an ACKNOWLEDGE to signal the slave that it wants more data. When the master has all the data it requires, it issues a NOT ACKNOWLEDGE and a STOP to end the transmission.

The continuous read from sequential registers protocol is as follows:

1. The master sends a START command.
2. The master sends the 7-bit slave address followed by a write bit (R/$\overline{W}$ = 0).
3. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
4. The master sends an 8-bit register pointer.
5. The slave acknowledges the register pointer.
6. The master sends a REPEATED START command.
7. The master sends the 7-bit slave address followed by a read bit (R/$\overline{W}$ = 1).
8. The addressed slave asserts an ACKNOWLEDGE by pulling SDA low.
9. The addressed slave places 8-bits of data on the bus from the location specified by the register pointer.
10. The master issues an ACKNOWLEDGE signaling the slave that it wishes to receive more data.
11. Steps 9 to 10 are repeated as many times as the master requires. Following the last byte of data, the master must issue a NOT ACKNOWLEDGE to signal that it wishes to stop receiving data.
12. The master sends a STOP condition or a REPEATED START condition. Issuing a STOP ensures that the bus input filters are set for 1MHz or slower operation. Issuing a REPEATED START leaves the bus input filters in their current state.

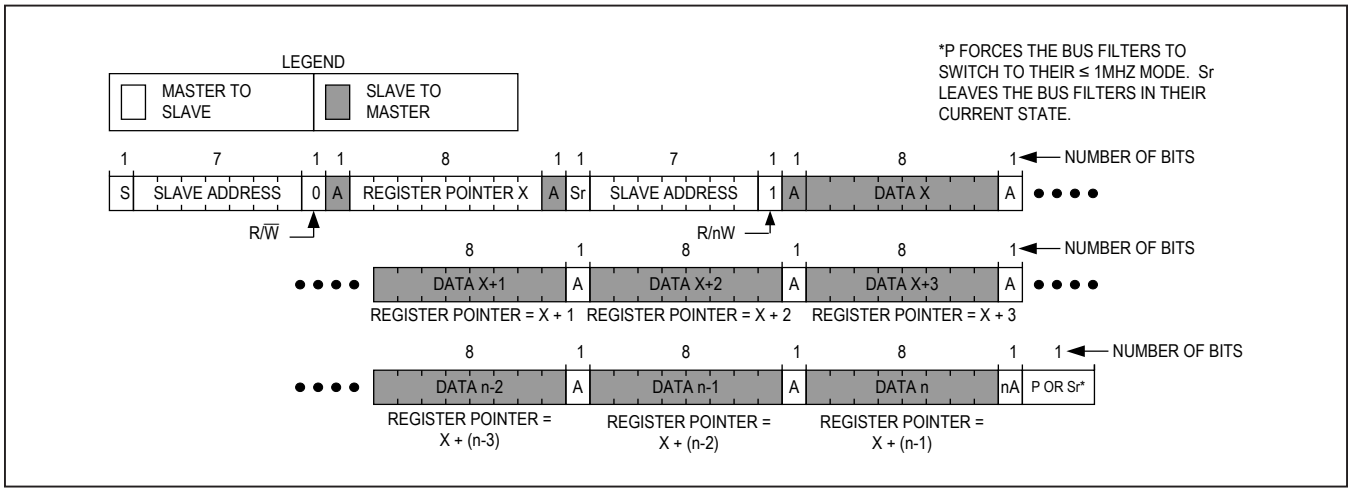


Figure 13. Reading Continuously from Sequential Registers X to N

Engaging HS Mode for Operation Up to 3.4MHz

Figure 14 shows the protocol for engaging HS mode operation. HS mode operation allows for a bus operating speed up to 3.4MHz.

The engaging HS mode protocol is as follows:

1. Begin the protocol while operating at a bus speed of 1MHz or lower
2. The master sends a START command.
3. The master sends the 8-bit master code of 00001xxxb where xxxb are don't care bits.
4. The addressed slave issues a NOT ACKNOWLEDGE.
5. The master can now increase its bus speed up to 3.4MHz and issue any read/write operation.

The master may continue to issue high-speed read/write operations until a STOP is issued. Issuing a STOP (P) ensures that the bus input filters are set for 1MHz or slower operation.

Registers

Register Reset Conditions

- Type O: Registers are reset when V_{SYS} < V = low

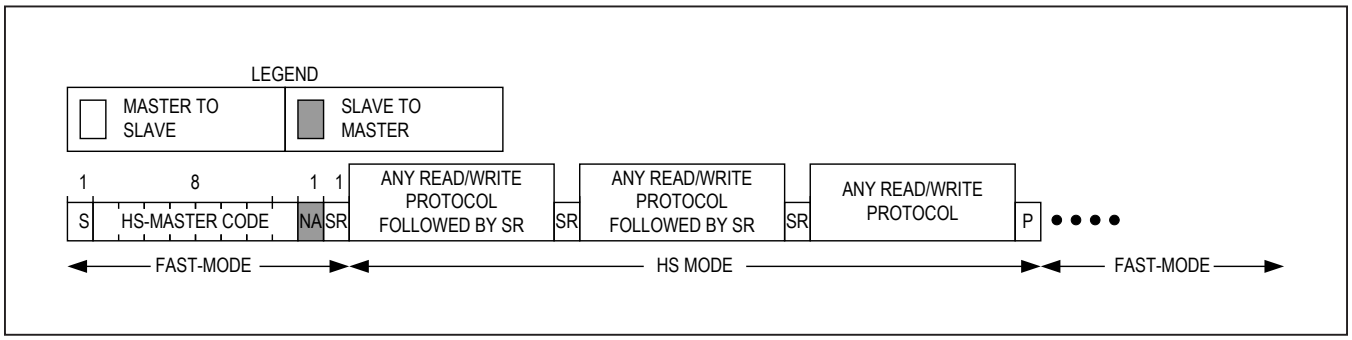


Figure 14. Engaging HS Mode

Register Map

I2C Slave Address (W/R): 0x30/0x31 (default)

ADDRESS	REGISTER NAME	RESET TYPE	R/W	BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0	RESET VALUE
0x00	DEVICE_ID	TypeO	R	RESERVED	VERSION[3:0]				CHIP_REV[2:0]			—
0x01	STATUS	TypeO	R	RESERVED	RESERVED	RESERVED	RESERVED	TSHDN	BB_POKn	BB_OVP	BB_OCP	—
0x02	CONFIG1	TypeO	R/W	RESERVED	RESERVED	BB_RU_SR	BB_RD_SR	BB_OVP_TH[1:0]		BB_AD	BB_FPWM	0x0E
0x03	CONFIG2	TypeO	R/W	RESERVED	BB_EN	EN_PD	POK_POL	RESERVED	RESERVED	RESERVED	RESERVED	0x70
0x04	VOUT_DVS_L	TypeO	R/W	RESERVED	VOUT_DVS_L[6:0]							0x38
0x05	VOUT_DVS_H	TypeO	R/W	RESERVED	VOUT_DVS_H[6:0]							0x40 0x5C
0x09–0xFF	RESERVED											

DEVICE_ID

Device ID Register

ADDRESS	MODE		TYPE: O	RESET VALUE: N/A
0x00	R			
BIT	NAME	POR	DESCRIPTION	
7	RESERVED	0		
6:3	VERSION[3:0]	—	Version 0000b: Plain 0001b: -1Z 0010b: -2Z	
2:0	CHIP_REV[2:0]	—	Chip revision history 001b: PASS1 010b: PASS2 011b: PASS3 and so on	

STATUS

Status Register

ADDRESS	MODE		TYPE: O	RESET VALUE: N/A
0x01	R			
BIT	NAME	POR	DESCRIPTION	
7:4	RESERVED	—		
3	TSHDN	—	0: Junction Temperature (TJCT) ≤ 165°C 1: Junction Temperature (TJCT) > 165°C	
2	BB_POKn	—	Buck-boost $\overline{\text{POK}}$ Status	
1	BB_OVP	—	Buck-boost OVP Status	
0	BB_OCP	—	Buck-boost OCP Status	

CONFIG1

Configuration Register1

ADDRESS	MODE		TYPE: O	RESET VALUE: 0x0E
0x02	R/W			
BIT	NAME	POR	DESCRIPTION	
7:6	RESERVED	00		
5	BB_RU_SR	0	**Rising Ramp-Rate Control** 0: 12.5mV/µs 1: 25mV/µs	
4	BB_RD_SR	0	**Ramp-Down Slew Rate Control** 0: 3.125mV/µs 1: 6.25mV/µs	
3:2	BB_OVP_TH[1:0]	11	**Output OVP Threshold** 00b: No OVP 01b: 110% of VOUT 10b: 115% of VOUT 11b: 120% of VOUT	
1	BB_AD	1	**Output Active Discharge** 0: Disable Active Discharge 1: Enable Active Discharge	
0	BB_FPWM	0	**Forced PWM Enable** 0: SKIP Mode 1: Forced PWM	

CONFIG2

Configuration Register2

ADDRESS	MODE		TYPE: O	RESET VALUE: 0x70
0x03	R/W			
BIT	NAME	POR	DESCRIPTION	
7	RESERVED	0		
6	BB_EN	1	0: Disable buck-boost output 1: Enable buck-boost output	
5	EN_PD	1	**EN Input Pulldown Resistor Enable Setting** 0: Disable 1: Enable	
4	POK_POL	1	0: Active low 1: Active high	
3:0	RESERVED	0000		

VOUT_DVS_L

Output Voltage Setting Register when DVS = low

ADDRESS	MODE		TYPE: O	RESET VALUE: 0x38		
0x04	R/W					
BIT	NAME	POR	DESCRIPTION			
7	RESERVED	0				
6:0	VOUT_DVS_L[6:0]	011 1000	**Buck-Boost Output Voltage**			
			0x00 = 2.6000V	0x20 = 3.0000V	0x40 = 3.4000V	0x60 = 3.8000V
			0x01 = 2.6125V	0x21 = 3.0125V	0x41 = 3.4125V	0x61 = 3.8125V
			0x02 = 2.6250V	0x22 = 3.0250V	0x42 = 3.4250V	0x62 = 3.8250V
			0x03 = 2.6375V	0x23 = 3.0375V	0x43 = 3.4375V	0x63 = 3.8375V
			0x04 = 2.6500V	0x24 = 3.0500V	0x44 = 3.4500V	0x64 = 3.8500V
			0x05 = 2.6625V	0x25 = 3.0625V	0x45 = 3.4625V	0x65 = 3.8625V
			0x06 = 2.6750V	0x26 = 3.0750V	0x46 = 3.4750V	0x66 = 3.8750V
			0x07 = 2.6875V	0x27 = 3.0875V	0x47 = 3.4875V	0x67 = 3.8875V
			0x08 = 2.7000V	0x28 = 3.1000V	0x48 = 3.5000V	0x68 = 3.9000V
			0x09 = 2.7125V	0x29 = 3.1125V	0x49 = 3.5125V	0x69 = 3.9125V
			0x0A = 2.7250V	0x2A = 3.1250V	0x4A = 3.5250V	0x6A = 3.9250V
			0x0B = 2.7375V	0x2B = 3.1375V	0x4B = 3.5375V	0x6B = 3.9375V
			0x0C = 2.7500V	0x2C = 3.1500V	0x4C = 3.5500V	0x6C = 3.9500V
			0x0D = 2.7625V	0x2D = 3.1625V	0x4D = 3.5625V	0x6D = 3.9625V
			0x0E = 2.7750V	0x2E = 3.1750V	0x4E = 3.5750V	0x6E = 3.9750V
			0x0F = 2.7875V	0x2F = 3.1875V	0x4F = 3.5875V	0x6F = 3.9875V
			0x10 = 2.8000V	0x30 = 3.2000V	0x50 = 3.6000V	0x70 = 4.0000V
			0x11 = 2.8125V	0x31 = 3.2125V	0x51 = 3.6125V	0x71 = 4.0125V
			0x12 = 2.8250V	0x32 = 3.2250V	0x52 = 3.6250V	0x72 = 4.0250V
			0x13 = 2.8375V	0x33 = 3.2375V	0x53 = 3.6375V	0x73 = 4.0375V
			0x14 = 2.8500V	0x34 = 3.2500V	0x54 = 3.6500V	0x74 = 4.0500V
			0x15 = 2.8625V	0x35 = 3.2625V	0x55 = 3.6625V	0x75 = 4.0625V
			0x16 = 2.8750V	0x36 = 3.2750V	0x56 = 3.6750V	0x76 = 4.0750V
			0x17 = 2.8875V	0x37 = 3.2875V	0x57 = 3.6875V	0x77 = 4.0875V
			0x18 = 2.9000V	**0x38 = 3.3000V**	0x58 = 3.7000V	0x78 = 4.1000V
			0x19 = 2.9125V	0x39 = 3.3125V	0x59 = 3.7125V	0x79 = 4.1125V
			0x1A = 2.9250V	0x3A = 3.3250V	0x5A = 3.7250V	0x7A = 4.1250V
			0x1B = 2.9375V	0x3B= 3.3375V	0x5B = 3.7375V	0x7B = 4.1375V
			0x1C = 2.9500V	0x3C = 3.3500V	0x5C = 3.7500V	0x7C = 4.1500V
			0x1D = 2.9625V	0x3D = 3.3625V	0x5D = 3.7625V	0x7D = 4.1625V
			0x1E = 2.9750V	0x3E = 3.3750V	0x5E = 3.7750V	0x7E = 4.1750V
			0x1F = 2.9875V	0x3F = 3.3875V	0x5F = 3.7875V	0x7F = 4.1875V

VOUT_DVS_H

Output Voltage Setting Register when DVS = high

ADDRESS	MODE		TYPE: O	RESET VALUE: 0x40 (WLP) 0x5C (TQFN)		
0x05	R/W					
BIT	NAME	POR	DESCRIPTION			
7	RESERVED	0				
6:0	VOUT_DVS_H[6:0]	011 1000	**Buck-Boost Output Voltage**			
			0x00 = 2.6000V	0x20 = 3.0000V	**0x40 = 3.4000V**	0x60 = 3.8000V
			0x01 = 2.6125V	0x21 = 3.0125V	0x41 = 3.4125V	0x61 = 3.8125V
			0x02 = 2.6250V	0x22 = 3.0250V	0x42 = 3.4250V	0x62 = 3.8250V
			0x03 = 2.6375V	0x23 = 3.0375V	0x43 = 3.4375V	0x63 = 3.8375V
			0x04 = 2.6500V	0x24 = 3.0500V	0x44 = 3.4500V	0x64 = 3.8500V
			0x05 = 2.6625V	0x25 = 3.0625V	0x45 = 3.4625V	0x65 = 3.8625V
			0x06 = 2.6750V	0x26 = 3.0750V	0x46 = 3.4750V	0x66 = 3.8750V
			0x07 = 2.6875V	0x27 = 3.0875V	0x47 = 3.4875V	0x67 = 3.8875V
			0x08 = 2.7000V	0x28 = 3.1000V	0x48 = 3.5000V	0x68 = 3.9000V
			0x09 = 2.7125V	0x29 = 3.1125V	0x49 = 3.5125V	0x69 = 3.9125V
			0x0A = 2.7250V	0x2A = 3.1250V	0x4A = 3.5250V	0x6A = 3.9250V
			0x0B = 2.7375V	0x2B = 3.1375V	0x4B = 3.5375V	0x6B = 3.9375V
			0x0C = 2.7500V	0x2C = 3.1500V	0x4C = 3.5500V	0x6C = 3.9500V
			0x0D = 2.7625V	0x2D = 3.1625V	0x4D = 3.5625V	0x6D = 3.9625V
			0x0E = 2.7750V	0x2E = 3.1750V	0x4E = 3.5750V	0x6E= 3.9750V
			0x0F = 2.7875V	0x2F = 3.1875V	0x4F = 3.5875V	0x6F = 3.9875V
			0x10 = 2.8000V	0x30 = 3.2000V	0x50 = 3.6000V	0x70 = 4.0000V
			0x11 = 2.8125V	0x31 = 3.2125V	0x51 = 3.6125V	0x71 = 4.0125V
			0x12 = 2.8250V	0x32 = 3.2250V	0x52 = 3.6250V	0x72 = 4.0250V
			0x13 = 2.8375V	0x33 = 3.2375V	0x53 = 3.6375V	0x73 = 4.0375V
			0x14 = 2.8500V	0x34 = 3.2500V	0x54 = 3.6500V	0x74 = 4.0500V
			0x15 = 2.8625V	0x35 = 3.2625V	0x55 = 3.6625V	0x75 = 4.0625V
			0x16 = 2.8750V	0x36 = 3.2750V	0x56 = 3.6750V	0x76 = 4.0750V
			0x17 = 2.8875V	0x37 = 3.2875V	0x57 = 3.6875V	0x77 = 4.0875V
			0x18 = 2.9000V	0x38 = 3.3000V	0x58 = 3.7000V	0x78 = 4.1000V
			0x19 = 2.9125V	0x39 = 3.3125V	0x59 = 3.7125V	0x79 = 4.1125V
			0x1A = 2.9250V	0x3A = 3.3250V	0x5A = 3.7250V	0x7A = 4.1250V
			0x1B = 2.9375V	0x3B = 3.3375V	0x5B = 3.7375V	0x7B = 4.1375V
			0x1C = 2.9500V	0x3C = 3.3500V	**0x5C = 3.7500V**	0x7C = 4.1500V
			0x1D = 2.9625V	0x3D = 3.3625V	0x5D = 3.7625V	0x7D = 4.1625V
			0x1E = 2.9750V	0x3E = 3.3750V	0x5E = 3.7750V	0x7E = 4.1750V
			0x1F = 2.9875V	0x3F = 3.3875V	0x5F = 3.7875V	0x7F = 4.1875V

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX77801EWP+T	-40°C to +85°C	20 WLP
MAX77801ETP+T	-40°C to +85°C	20 TQFN

+Denotes a lead(Pb)-free/RoHS-compliant package.
T = Tape and reel.

Package Information

For the latest package outline information and land patterns (footprints), go to **www.maximintegrated.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
20 WLP	W201F2+1	**21-0771**	Refer to **Application Note 1891**
20 TQFN	T2044-3C	**21-0139**	**90-0037**

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	2/15	Initial release	—
1	4/17	Added MAX77801ETP TQFN package information, updated *Benefits and Features* section, updated *Communication Protocals* sections, updated Figures 10–12, updated tables for *Package Thermal Characteristics*, *Buck-Boost Electrical Characteristics*, *Register Map*, *VOUT_DVS_H*, *Ordering Information*, and *Package Information*	1–3, 8, 14–19, 23, 24
2	2/18	Corrected a typo in Figure 5	11
3	3/18	Added MAX77801ETP default V_{OUT} to *Electrical Characteristics* table	2

